

# SB10150LCT

Unit: inch ( mm )

## DUAL LOW VF SCHOTTKY RECTIFIER

**VOLTAGE** 150 Volts **CURRENT** 10 Amperes

### FEATURES

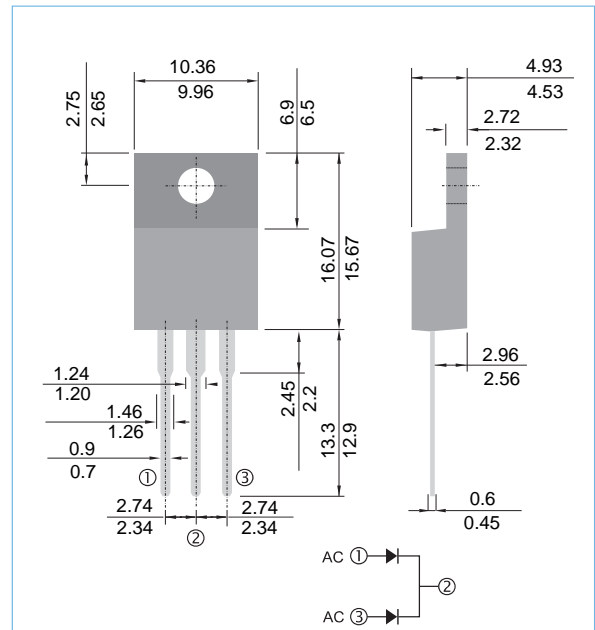
- Low forward voltage drop, low power losses
- High efficiency operation
- In compliance with EU RoHS 2002/95/EC directives

### MECHANICAL DATA

Case : TO-220AB, Plastic

Terminals : Solderable per MIL-STD-750, Method 2026

Weight: 0.0655 ounces, 1.859 grams.



### MAXIMUM RATINGS( $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	VALUE	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	150	V
Maximum average forward rectified current (Fig.3)	$I_{F(AV)}$	10 5	A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load per diode	$I_{FSM}$	200	A
Typical thermal resistance	$R_{\theta JC}$	2.5	$^{\circ}\text{C/W}$
Operating junction	$T_J$	-55 to + 150	$^{\circ}\text{C}$
Storage temperature range	$T_{STG}$	-55 to + 150	$^{\circ}\text{C}$

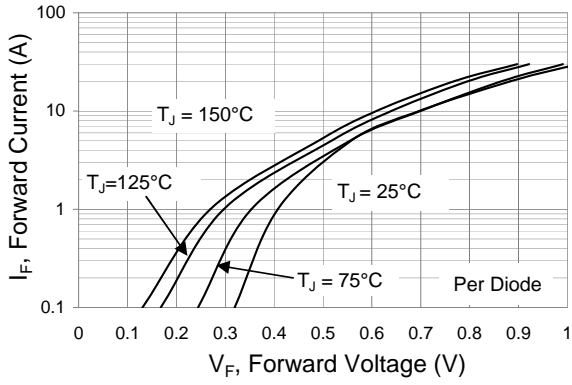
### ELECTRICAL CHARACTERISTICS( $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Breakdown voltage per diode	$V_{BR}$	$I_R=1.0\text{mA}$	103	120	-	V
Instantaneous forward voltage per diode <sup>(1)</sup>	$V_F$	$I_F=5\text{A}$ $I_F=10\text{A}$	-	0.55 -	0.60 0.75	V
		$I_F=5\text{A}$ $I_F=10\text{A}$	-	0.52 0.62	- 0.70	V
Reverse current per diode <sup>(2)</sup>	$I_R$	$V_R=70\text{V}$	-	10	35	$\mu\text{A}$
		$V_R=100\text{V}$	-	-	500 30	$\mu\text{A}$ mA

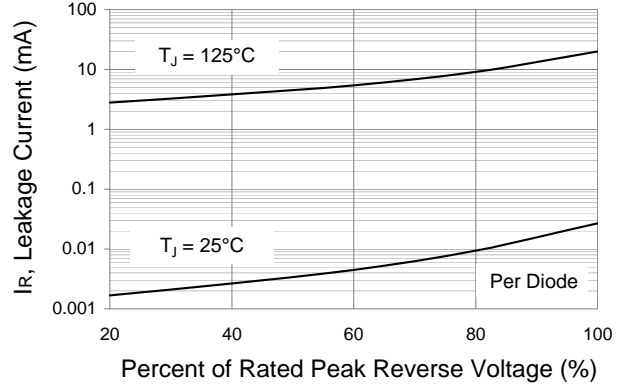
Note.1 Pulse test : 380 $\mu\text{s}$  pulse width, 1% duty cycle

2. Pulse test : Pulse width  $\leq 2.5\text{ms}$

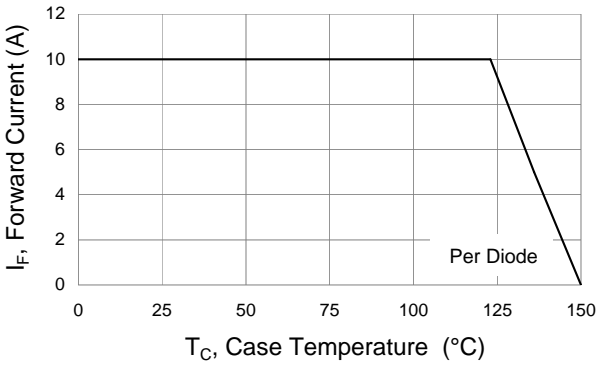
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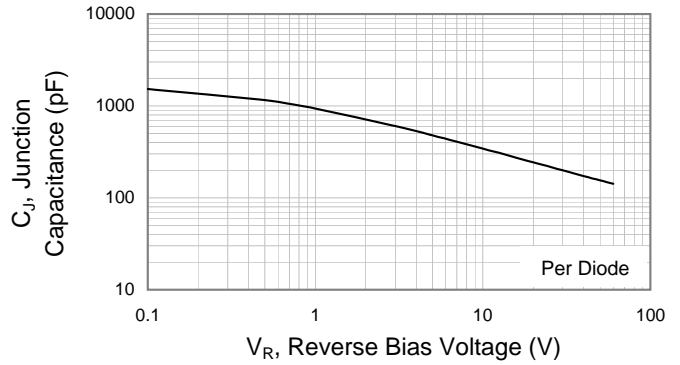
**Fig.1 Typical Forward Characteristics**



**Fig.2 Typical Reverse Characteristics**



**Fig.3 Forward Current Derating Curve**



**Fig.4 Typical Junction Capacitance**